



# N-Channel 30-V (D-S) Fast Switching MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
30	0.0065 at V <sub>GS</sub> = 10 V	21		
	0.008 at V <sub>GS</sub> = 4.5 V	19		

### **FEATURES**

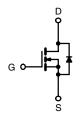
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET<sup>®</sup> Power MOSFET
- New Low Thermal Resistance PowerPAK<sup>®</sup> Package with Low 1.07 mm Profile
- 100 % R<sub>a</sub> Tested





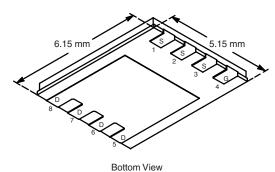
### **APPLICATIONS**

- DC/DC Converters
- Optimized for "Low-Side" Synchronous Rectifier Operation



N-Channel MOSFET

#### PowerPAK SO-8



Ordering Information: Si7440DP-T1-E3 (Lead (Pb)-free)

Si7440DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		$V_{DS}$	30		V	
Gate-Source Voltage		$V_{GS}$	± 20			
Continuous Drain Current (T = 150°C)8	T <sub>A</sub> = 25°C	I <sub>D</sub>	21	12	Δ	
Continuous Drain Current (T <sub>J</sub> = 150°C) <sup>a</sup>	T <sub>A</sub> = 70°C		17	9		
Pulsed Drain Current		I <sub>DM</sub>	60		Α	
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	4.3	1.6		
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25°C	P <sub>D</sub>	5.4	1.9	W	
Maximum Fower Dissipation	T <sub>A</sub> = 70°C		3.4	1.2		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) <sup>b, c</sup>		, and the second	260			

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Manifestor Lorentine to Application	t ≤ 10 s	- R <sub>thJA</sub>	18	23	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		52	65		
Maximum Junction-to-Case (Drain)	Steady State	R <sub>thJC</sub>	1.0	1.3		

#### Notes

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (<u>www.vishay.com/ppg?73257</u>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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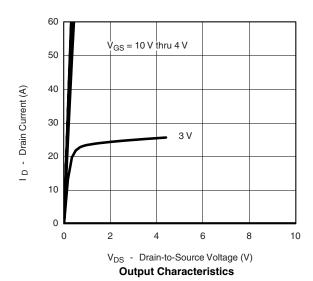
Parameter Symbol		Test Conditions	Min.	Тур.	Max.	Unit
Static	•					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0		3.0	V
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			1	μΑ
		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			5	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α
Drain-Source On-State Resistance <sup>a</sup>		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 21 A		0.0053	0.0065	0
	R <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 19 \text{ A}$		0.0065	0.008	Ω
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 21 A		65		S
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = 4.3 A, V <sub>GS</sub> = 0 V		0.72	1.2	V
Dynamic <sup>b</sup>						
Total Gate Charge	Qg			29.0	35	
Gate-Source Charge	$Q_{gs}$ $V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 21 \text{ A}$ $Q_{gd}$		10.5		nC	
Gate-Drain Charge				10.0		
Gate Resistance	$R_{g}$		0.5	1.4	2.2	Ω
Turn-On Delay Time	t <sub>d(on)</sub>			18	28	
Rise Time	t <sub>r</sub>	$t_r$ $V_{DD} = 15 \text{ V}, R_L = 15 \Omega$		16	25	ns
Turn-Off Delay Time	$t_{d(off)}$ $I_D \cong 1.0 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		75	180		
Fall Time	t <sub>f</sub>			41	65	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = 4.3 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		50	80	

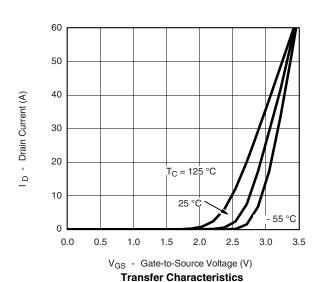
#### Notes

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



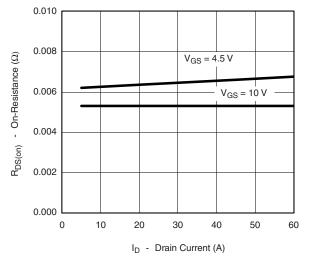




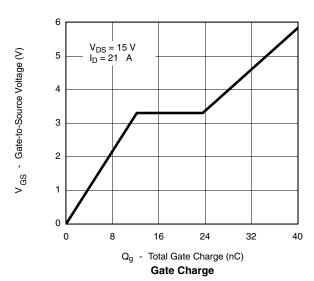




## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



#### On-Resistance vs. Drain Current



T<sub>J</sub> = 150 °C

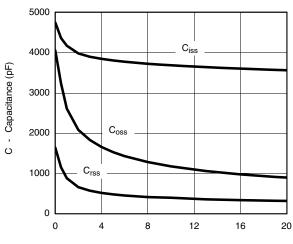
T<sub>J</sub> = 150 °C

T<sub>J</sub> = 25 °C

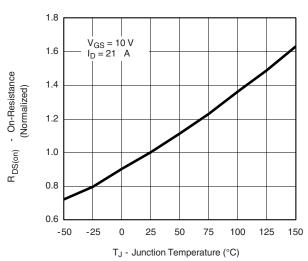
T<sub>J</sub> = 25 °C

V<sub>SD</sub> - Source-to-Drain Voltage (V)

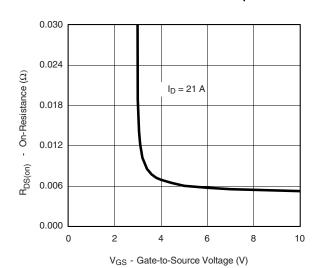
Source-Drain Diode Forward Voltage



V<sub>DS</sub> - Drain-to-Source Voltage (V) **Capacitance** 



On-Resistance vs. Junction Temperature



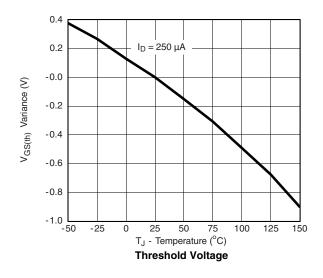
On-Resistance vs. Gate-to-Source Voltage

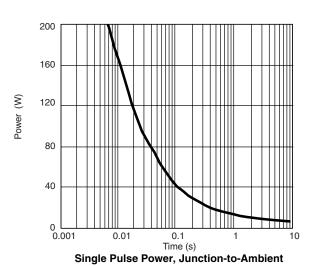
Is - Source Current (A)

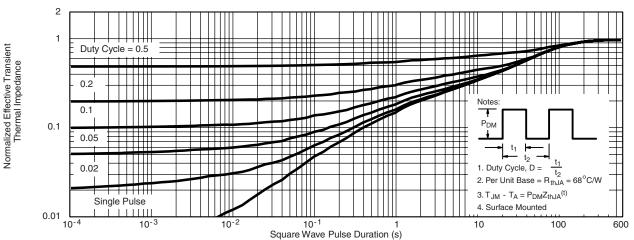
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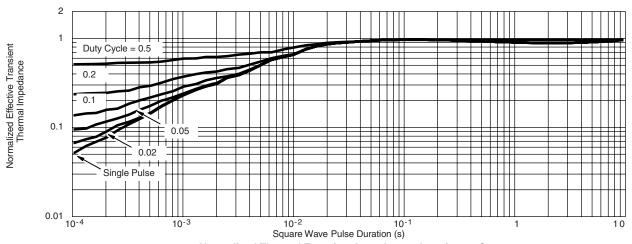
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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